# **BLP10H603**

# **Broadband LDMOS driver transistor**

**AMMPLEON** 

Rev. 2 — 1 September 2015

Product data sheet

#### **Product profile** 1.

### 1.1 General description

A 2.5 W plastic LDMOS power transistor for broadcast transmitter and ISM applications at frequencies from HF to 1400 MHz.

Table 1. **Application performance** 

Test signal	f	V <sub>DS</sub>	$P_L$	Gp	$\eta_D$
	(MHz)	(V)	(W)	(dB)	(%)
CW	860	50	2.5	22.8	62

### 1.2 Features and benefits

- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 1400 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

### 1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications

### **Broadband LDMOS driver transistor**

# 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1, 2, 4, 5, 6, 7, 8, 9, 11, 12	n.c.	1 12	10 I
3	gate1	2	<u> </u>
10	drain1		3 —
13	source [1]	Transparent top view	13 aaa-012010

[1] Connected to flange.

# 3. Ordering information

Table 3. Ordering information

Type number	Package	Package				
	Name	Description	Version			
BLP10H603	HVSON12	plastic thermal enhanced very thin small outline package; no leads; 12 terminals; body $5\times6\times0.85$ mm	SOT1352-1			

# 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	104	V
$V_{GS}$	gate-source voltage		-6	+11	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C

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## 5. Recommended operating conditions

See application note AN11520 for more details.

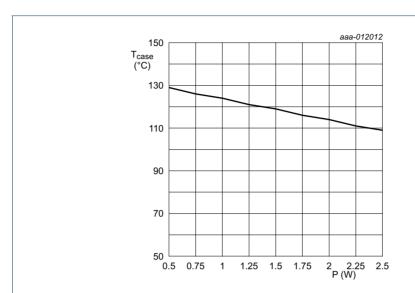


Fig 1. Recommended operating area; case temperature as a function of power dissipation

### 6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case	$T_{case} = 80  ^{\circ}C; P_{L} = 2.5  W  ^{11}$	9.9	K/W

<sup>[1]</sup>  $R_{th(j-c)}$  is measured under RF conditions

### 7. Characteristics

Table 6. DC characteristics

 $T_j = 25$  °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.03 \text{ mA}$	104	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_D = 3 \text{ mA}$	1.25	1.65	2.25	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS} = 50 \text{ V}; I_D = 15 \text{ mA}$	1.3	1.73	2.15	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 50 V	-	-	1.4	μА
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	0.5	-	Α
$I_{GSS}$	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	140	nA
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 105 \text{ mA}$	-	9	-	Ω

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Table 7. AC characteristics

 $T_i = 25$  °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C <sub>rs</sub>	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	0.03	-	pF
C <sub>iss</sub>	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 0 \text{ V}; f = 1 \text{ MHz}$	-	3.4	-	pF
Coss	output capacitance	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 50 V; f = 1 MHz	-	1.12	-	pF

#### Table 8. RF characteristics

Test signal: pulsed CW; f = 860 MHz; RF performance at  $V_{DS} = 50$  V;  $I_{Dq} = 15$  mA;  $t_p = 50$   $\mu$ s;  $\delta = 10$  %;  $T_{case} = 25$  °C; unless otherwise specified, in a class-AB production test circuit [1].

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P <sub>L</sub> = 2.5 W	21.4	22.8	25.5	dB
$\eta_{D}$	drain efficiency	P <sub>L</sub> = 2.5 W	60	62	-	%

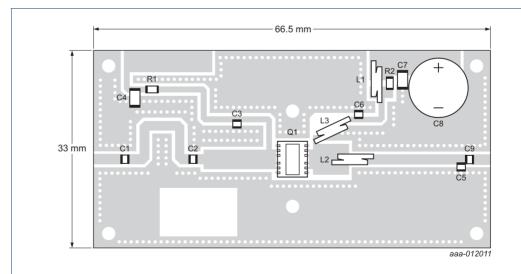
<sup>[1]</sup> The industrial test method is performed on special hardware to accommodate the requirements of production. The test results in this table are correlated to correspond with a performance in the application.

### 8. Test information

### 8.1 Ruggedness in class-AB operation

The BLP10H603 is capable of withstanding a load mismatch corresponding to VSWR = 35 : 1 through all phases under the following conditions:  $V_{DS}$  = 50 V;  $I_{Dq}$  = 15 mA;  $P_{L}$  = 2.5 W; f = 860 MHz.

#### 8.2 Test circuit



Printed-Circuit Board (PCB): Rogers RO4350;  $\epsilon_{\text{r}}$  = 3.48; height = 0.762 mm; thickness copper plating = 35  $\mu$ m.

See Table 9 for a list of components.

### Fig 2. Component layout

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**Table 9. List of components** See Figure 2 for component layout.

Component	Description	Value		Remarks
C1, C3, C6, C9	multilayer ceramic chip capacitor	100 pF	[1]	
C2	multilayer ceramic chip capacitor	3.9 pF	[1]	
C4	multilayer ceramic chip capacitor	1 μF, 25 V		Murata GRM31MR71E105KA01L
C5	multilayer ceramic chip capacitor	4.7 pF	[1]	
C7	multilayer ceramic chip capacitor	1 μF, 50 V		Murata GRM32RR71H105KA01L
C8	electrolytic capacitor	220 μF, 63 V		
L1	wire inductor, 0.8 mm copper wire	2 turn, D = 3 mm		
L2	wire inductor, 0.8 mm copper wire	2 turn, D = 2.7 mm		
L3	wire inductor, 0.8 mm copper wire	2 turn, D = 3 mm		
R1	resistor	0 Ω		SMD 0805
R2	resistor	10 Ω		SMD 0805
Q1	transistor	-		BLP10H603

<sup>[1]</sup> American Technical Ceramics type 100A or capacitor of same quality.

### 8.3 Graphical data

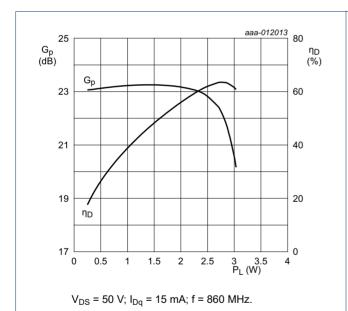
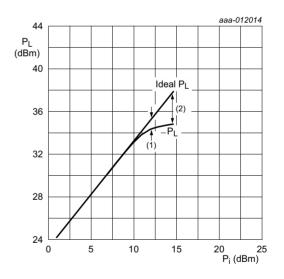


Fig 3. Power gain and drain efficiency as function of output power; typical values

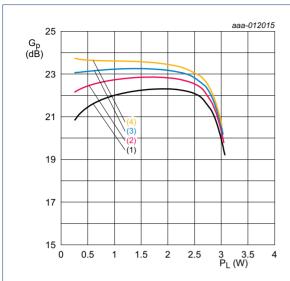


 $V_{DS} = 50 \text{ V}$ ;  $I_{Dq} = 15 \text{ mA}$ ; f = 860 MHz.

- (1)  $P_{L(1dB)} = 34.4 \text{ dBm } (2.8 \text{ W})$
- (2)  $P_{L(3dB)} = 34.8 \text{ dBm } (3.0 \text{ W})$

Fig 4. Output power as a function of input power; typical values

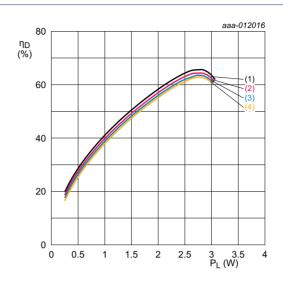
### **Broadband LDMOS driver transistor**



V<sub>DS</sub> = 50 V; f = 860 MHz.

- (1)  $I_{Dq} = 5 \text{ mA}$
- (2)  $I_{Dq} = 10 \text{ mA}$
- (3)  $I_{Dq} = 15 \text{ mA}$
- (4)  $I_{Dq} = 20 \text{ mA}$

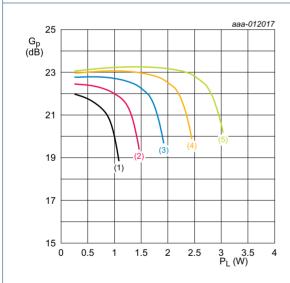
Fig 5. Power gain as a function of output power; typical values



 $V_{DS} = 50 \text{ V}; f = 860 \text{ MHz}.$ 

- (1)  $I_{Dq} = 5 \text{ mA}$
- (2)  $I_{Dq} = 10 \text{ mA}$
- (3)  $I_{Dq} = 15 \text{ mA}$
- (4)  $I_{Dq} = 20 \text{ mA}$

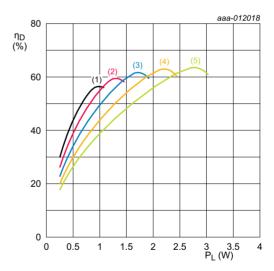
Fig 6. Drain efficiency as a function of output power; typical values



 $I_{Dq} = 15 \text{ mA}$ ; f = 860 MHz.

- (1)  $V_{DS} = 30 \text{ V}$
- (2)  $V_{DS} = 35 V$
- (3)  $V_{DS} = 40 \text{ V}$
- (4)  $V_{DS} = 45 \text{ V}$
- (5)  $V_{DS} = 50 \text{ V}$

Fig 7. Power gain as a function of output power; typical values



 $I_{Dq} = 15 \text{ mA}$ ; f = 860 MHz.

- (1)  $V_{DS} = 30 \text{ V}$
- (2)  $V_{DS} = 35 V$
- (3)  $V_{DS} = 40 \text{ V}$
- (4)  $V_{DS} = 45 \text{ V}$
- (5)  $V_{DS} = 50 \text{ V}$

Fig 8. Drain efficiency as a function of output power; typical values

### **Broadband LDMOS driver transistor**

# 9. Package outline

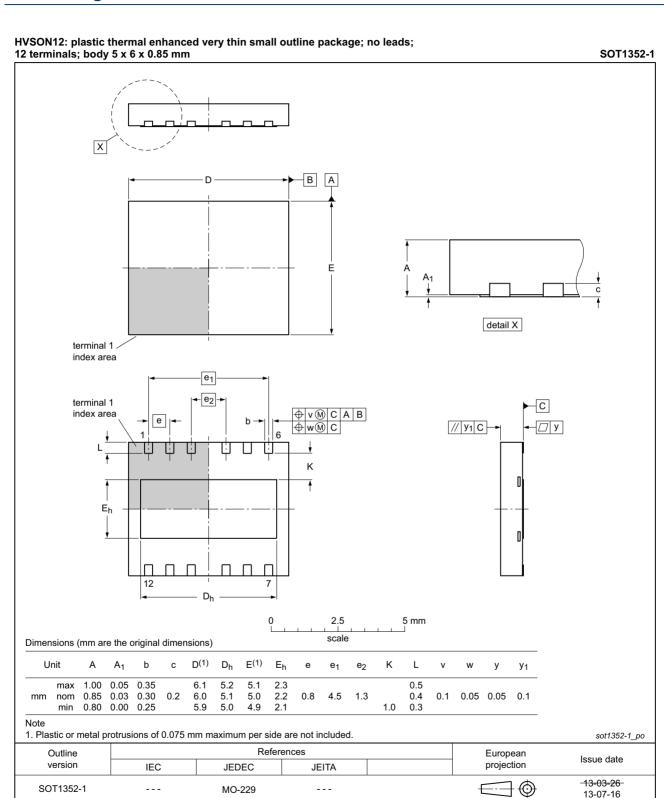


Fig 9. Package outline SOT1352-1 (HVSON12)

### **Broadband LDMOS driver transistor**

# 10. Handling information

### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

# 11. Abbreviations

Table 10. Abbreviations

Acronym	Description	
CW	Continuous Wave	
ESD	ElectroStatic Discharge	
LDMOS	Laterally Diffused Metal-Oxide Semiconductor	
HF	High Frequency	
ISM	Industrial, Scientific and Medical	
SMD	Surface Mounted Device	
VSWR	Voltage Standing-Wave Ratio	

# 12. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLP10H603#2	20150901	Product data sheet		BLP10H603 v.1	
Modifications:	The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.				
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>				
BLP10H603 v.1	20141002	Product data sheet	-	-	

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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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